

iscN-Channel MOSFET Transistor

TK6A60D

• FEATURES

- Low drain-source on-resistance:
 R_{DS}(ON) = 1.25Ω (MAX)
- Enhancement mode:
 Vth = 2 to 4V (VDS = 10 V, ID=1.0mA)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

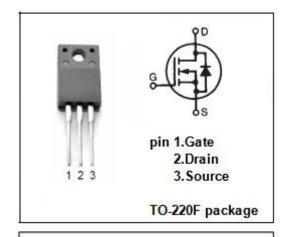
· Switching Voltage Regulators

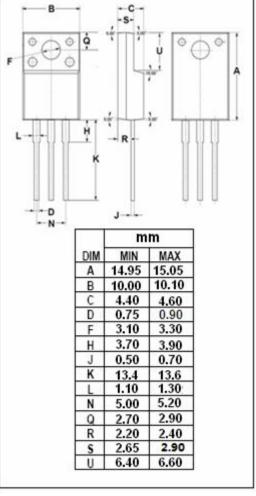
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|------------|------|
| V _{DSS} | Drain-Source Voltage | 600 | V |
| V _{GS} | Gate-Source Voltage | ٧ | |
| l _D | Drain Current-Continuous | Α | |
| I _{DM} | Drain Current-Single Pulsed | 24 | Α |
| P _D | Total Dissipation @T _C =25°C 40 | | W |
| Tj | Max. Operating Junction Temperature | rature 150 | |
| T _{stg} | Storage Temperature | -55~150 | ℃ |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|------------------------------------|-------|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 3.125 | °C/W |





isc website: www.iscsemi.cn

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNIT |
|---------------------|--------------------------------|--|-----|-----|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D = 10mA | 600 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = 10V; I _D =1.0mA | 2 | | 4 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D =3A | | | 1.25 | Ω |
| lgss | Gate-Source Leakage Current | V _{GS} = ±30V;V _{DS} = 0V | | | ±1 | μА |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =600V; V _{GS} = 0V | | | 10 | μА |
| V_{SDF} | Diode forward voltage | I_{DR} =6A, V_{GS} = 0 V | | | 1.7 | V |



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